

NEW ENGLAND SEMICONDUCTOR

BIPOLAR PNP TRANSISTOR TO-66

PACKAGE	DEVICE TYPE	V _{CEO} (sus) VOLTS	I _C (max) AMPS	h _{FE} @ I _C /V _{CE} (min/max @ A/V)	V _{CE(sat)} @ I _C /I _B (V @ A/A)	P _D * WATTS	f _T (MHz)
PNP TO-66 	2N3740^	60	1	30-100@.25/1	.6@1/.125	25	4
	2N3740A	60	1	30-100@.25/1	.6@1/.125	25	4
	2N3741^	80	1	30-100@.25/1	.6@1/.125	25	4
	2N3741A	80	1	30-100@.25/1	.6@1/.125	25	4
	2N4898	40	1	20-100@.5/1	.6@1/.1	25	3
	2N4899	60	1	20-100@.5/1	.6@1/.1	25	3
	2N4900	80	1	20-100@.5/1	.6@1/.1	25	3
	2N5954	80	6	20-100@2/4	1@2/.2	40	5
	2N5955	80	6	20-100@2.5/4	1@2.5/.25	40	5
	2N5956	40	6	20-100@3/4	1@3/.3	40	5
	2N6211^	250 ^h	2	10-100@1/2.8	1.4@1/.125	35	20
	2N6212^	325 ^h	2	10-100@1/3.2	1.6@1/.125	35	20
	2N6213^	375 ^h	2	10-100@1/4	2@1/.125	35	20
	2N6312	40	5	25-100@1.5/4	.7@1.5/.15	75	4
	2N6313	60	5	25-100@1.5/4	.7@1.5/.15	75	4
	2N6314	80	5	25-100@1.5/4	.7@1.5/.15	75	4
	2N6317	60	7	20-100@2.5/4	1@4/4	90	4
	2N6318	80	7	20-100@2.5/4	1@4/4	90	4

* T_C = 25°C

^h V_{CER}

^Available in JAN, JANTX, JANTXV